

23 ns and 65 ns Low Voltage Comparators

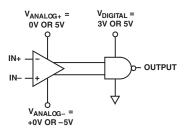
CMP401/CMP402

FEATURES

23 ns or 65 ns Propagation Delay Single-Supply Operation Compatible with 3 V and 5 V Logic Separate Input and Output Sections Low Power Wide Input Range: -5 V to +3.9 V

APPLICATIONS
Battery-Operated Instrumentation
Line Receivers
Level Translators
Read Channel Detection

FUNCTIONAL BLOCK DIAGRAM

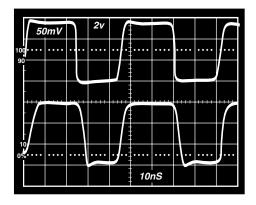


NOTE: $(V_{ANALOG+}) - (V_{ANALOG-}) \ge 3V$

GENERAL DESCRIPTION

The CMP401 and CMP402 are 23 ns and 65 ns quad comparators with separate input and output supplies. Separate supplies enable the input stage to be operated from +3 V to as high as ± 6 V. The output can be supplied with either 3 V or 5 V as determined by the interface logic or available supplies. Independent input and output supplies combined with fast propagation make the CMP401 and CMP402 excellent choices for interfacing to portable instrumentation.

The CMP401 and CMP402 are specified over the extended industrial (-40°C to +125°C) temperature range. Both are available in narrow 16-lead SOIC surface-mount packages and 16-lead TSSOP.



CMP401: 20 MHz Noninverting Switching, $V_{IN} = \pm 100 \text{ mV}$

CMP401/CMP402—SPECIFICATIONS

 $\textbf{ELECTRICAL SPECIFICATIONS} \ \ (@\ V+_{ANA}=V+_{DIG}=5.0\ V,\ V_{CM}=0.1\ V,\ -40^{\circ}C \le T_{A} \le +125^{\circ}C,\ unless\ otherwise\ noted.)$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS Offset Voltage ¹	V _{os} V _{os}	T _A = 25°C			3 4	mV mV
Hysteresis Input Bias Current	I_{B}	T _A = 25°C		2	3 4	mV μA μA
Input Offset Current Input Common-Mode Voltage Range Common-Mode Rejection Large-Signal Voltage Gain Offset Voltage Drift	$ \begin{vmatrix} I_{OS} \\ V_{CM} \\ CMRR \\ A_{VO} \\ \Delta V_{OS}/\Delta T \end{vmatrix} $	$0.1 \text{ V} \le \text{V}_{\text{CM}} \le 3.9 \text{ V}$ $R_{\text{L}} = 10 \text{ k}\Omega$	0 60	10 1	±3 4.0	μA V dB V/mV μV/°C
OUTPUT CHARACTERISTICS Output High Voltage Output Low Voltage	V _{OH} V _{OL}	I_{OH} = -3.2 mA I_{OL} = 3.2 mA	4.6	-	0.2	V V
POWER SUPPLY Power Supply Rejection Ratio Analog Supply Current – CMP401 Digital Supply Current – CMP401 Analog Supply Current – CMP401 Digital Supply Current – CMP401 Analog Supply Current – CMP401 Analog Supply Current – CMP402 Digital Supply Current – CMP402 Analog Supply Current – CMP402 Digital Supply Current – CMP402 Digital Supply Current – CMP402	PSRR I _{ANA} I _{DIG} I _{ANA}	$V+_{ANA} \text{ and } V+_{DIG} 2.7 \text{ V to 6 V}$ $T_A = 25^{\circ}\text{C}$ $V_O = 0 \text{ V, } R_L = \infty, T_A = 25^{\circ}\text{C}$ $V_O = 0 \text{ V, } R_L = \infty$ $T_A = 25^{\circ}\text{C}$ $V_O = 0 \text{ V, } R_L = \infty, T_A = 25^{\circ}\text{C}$ $V_O = 0 \text{ V, } R_L = \infty$	60		6.5 2.0 8.0 2.25 1.4 2.0 1.75 2.25	dB mA mA mA mA mA mA mA
DYNAMIC PERFORMANCE Propagation Delay – CMP401	t _P	100 mV Step with 20 mV OD $T_A = 25^{\circ}C$ 100 mV Step with 5 mV OD		17	23	ns
Propagation Delay – CMP402	t _P	$T_A = 25^{\circ}C$ 100 mV Step with 20 mV OD 100 mV Step with 20 mV OD		33	30	ns ns
	t _P	$T_A = 25^{\circ}C$ 100 mV Step with 5 mV OD $T_A = 25^{\circ}C$ 100 mV Step with 20 mV OD		54 60	65 75	ns ns ns

$\textbf{ELECTRICAL SPECIFICATIONS} \ \ (@V_{ANA} = V_{DIG} = 3.0 \ V, \ V_{CM} = 0.1 \ V, \ T_A = 25 ^{\circ}\text{C}, \ unless \ otherwise \ noted.)$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage ¹	Vos				4.5	mV
Input Common-Mode Voltage Range	V_{CM}		0		2.0	V
Input Differential Voltage Range	V_{DIFF}		±2.0			V
Common-Mode Rejection	CMRR	$0.1 \text{ V} \le \text{V}_{\text{CM}} \le 1.9 \text{ V}$	60			dB
OUTPUT CHARACTERISTICS						
Output High Voltage	V _{OH}	$I_{OH} = -3.2 \text{ mA}$	2.6			V
Output Low Voltage	V _{OL}	$I_{OL} = 3.2 \text{ mA}$			0.25	V
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V+_{ANA}$ and $V+_{DIG}$ 2.7 V to 6 V	60			dB
Analog Supply Current – CMP401	I _{ANA}				6	mA
Digital Supply Current - CMP401	I_{DIG}	$V_O = 0 V, R_L = \infty$			1	mA
Analog Supply Current – CMP402	I _{ANA}				1.2	mA
Digital Supply Current – CMP402	I_{DIG}	$V_O = 0 V, R_L = \infty$			1	mA
DYNAMIC PERFORMANCE						
Propagation Delay - CMP401	t _P	100 mV Step with 20 mV OD		32		ns
Propagation Delay - CMP402	t _P	100 mV Step with 20 mV OD		70		ns

ELECTRICAL SPECIFICATIONS (@ $V \pm_{ANA} = \pm 5$ V, $V_{DIG} = 5.0$ V, $T_A = 25$ °C, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage ¹	Vos	$V_{CM} = 0 \text{ V}$			3	mV
Input Common-Mode Voltage Range	V_{CM}		-5.0		+4.0	V
Input Differential Voltage Range	V_{DIFF}		±8.0			V
Common-Mode Rejection	CMRR	$-4.9 \text{ V} \le \text{V}_{\text{CM}} \le 3.9 \text{ V}$	60			dB
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			1	5	μV/°C
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{\pm ANA} \pm 3 \text{ V to } \pm 6 \text{ V}$	60			dB
Analog Supply Current - CMP401	I _{ANA}				6.5	mA
Digital Supply Current - CMP401	I_{DIG}	$V_O = 0 V, R_L = \infty$			2.0	mA
Analog Supply Current – CMP402	I _{ANA}				2.0	mA
Digital Supply Current – CMP402	I_{DIG}	$V_O = 0 V, R_L = \infty$			2.0	mA
DYNAMIC PERFORMANCE						
Propagation Delay - CMP401	t _P	100 mV Step with 20 mV OD			23	ns
Propagation Delay – CMP402	t _P	100 mV Step with 20 mV OD			65	ns

NOTES

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 $^{^{1}}$ Offset voltage is defined as $(V_{OS+} + V_{OS-})/2$.

Specifications subject to change without notice.

CMP401/CMP402

ABSOLUTE MAXIMUM RATINGS¹

Digital Supply Voltage	Total Analog Supply Voltage 16 V
$\begin{array}{llllllllllllllllllllllllllllllllllll$	Digital Supply Voltage 7 V
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Analog Positive Supply—Digital Positive Supply200 mV
Output Short-Circuit Duration to GND Indefinite Storage Temperature Range S, RU Package65°C to +150°C Operating Temperature Range CMP401G, CMP402G40°C to +125°C Junction Temperature Range S, RU Package65°C to +150°C	Input Voltage ²
Storage Temperature Range S, RU Package65°C to +150°C Operating Temperature Range CMP401G, CMP402G40°C to +125°C Junction Temperature Range S, RU Package	Differential Input Voltage ±9 V
S, RU Package65°C to +150°C Operating Temperature Range CMP401G, CMP402G40°C to +125°C Junction Temperature Range S, RU Package65°C to +150°C	Output Short-Circuit Duration to GND Indefinite
Operating Temperature Range CMP401G, CMP402G40°C to +125°C Junction Temperature Range S, RU Package65°C to +150°C	Storage Temperature Range
CMP401G, CMP402G40°C to +125°C Junction Temperature Range S, RU Package65°C to +150°C	S, RU Package –65°C to +150°C
Junction Temperature Range S, RU Package65°C to +150°C	Operating Temperature Range
S, RU Package65°C to +150°C	CMP401G, CMP402G40°C to +125°C
	Junction Temperature Range
Lead Temperature Range (Soldering 60 sec) 300°C	S, RU Package –65°C to +150°C
Zead Temperature Range (Goldering Golder) 500 G	Lead Temperature Range (Soldering 60 sec) 300°C

Package Type	θ_{JA}^{3}	$\theta_{ m JC}$	Units
16-Lead SOIC (S)	113	37	°C/W
16-Lead TSSOP (RU)	180	37	°C/W

NOTES

 $^{{}^{3}\}theta_{JA}$ is specified for the worst-case conditions, i.e., θ_{JA} is specified for device soldered in circuit board for SOIC and TSSOP packages.

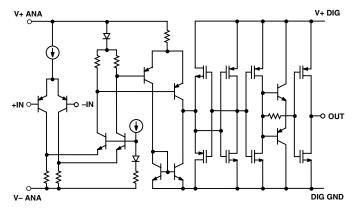
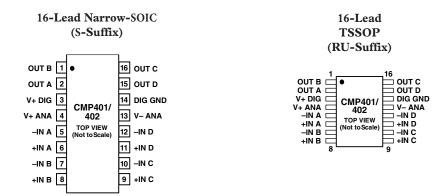


Figure 1. Simplified Schematic

PIN CONFIGURATIONS



CAUTION_

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the CMP401/CMP402 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



Revision History

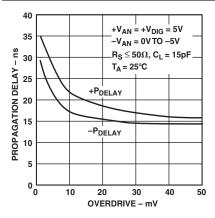
Location	Page	Location	Page	
Data Sheet changed from REV. A to REV. B.		Data Sheet changed from REV. 0 to REV. A.		
Changed SO-16 to 16-Lead SOICThrough	ghout	Edits to GENERAL DESCRIPTION	1	
Moved Revision History	4	Edits to ABSOLUTLE MAXIMUM RATING	GS4	
Moved Outline Dimensions	8	Edits to PACKAGE TYPE	4	
Updated Outline Dimensions	8	Edits to ORDERING GUIDE	4	
Changes to Ordering Guide	8	Deleted DICE CHARACTERISTICS	4	
		Edits to CMP401/CMP402 PIN CONFIRGU	JRATIONS 4	

-4- REV. B

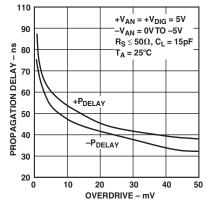
¹Absolute Maximum Ratings apply to packaged parts, unless otherwise noted.

 $^{^2} The$ analog input voltage is equal to $\pm 7~V$ or the analog supply voltage, whichever is less.

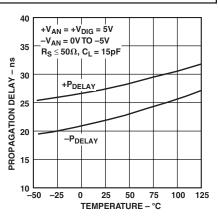
Typical Performance Characteristics—CMP401/CMP402



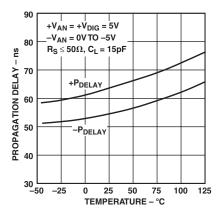
TPC 1. CMP401 Propagation Delay vs. Overdrive



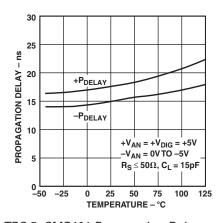
TPC 2. CMP402 Propagation Delay vs. Overdrive



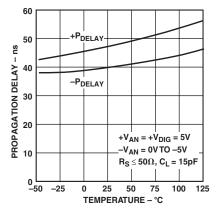
TPC 3. CMP401 Propagation Delay vs. Temperature – 5 mV OD



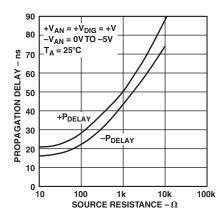
TPC 4. CMP402 Propagation Delay vs. Temperature – 5 mV OD



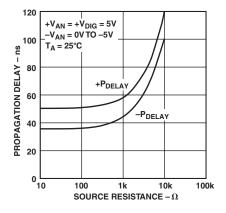
TPC 5. CMP401 Propagation Delay vs. Temperature – 20 mV OD



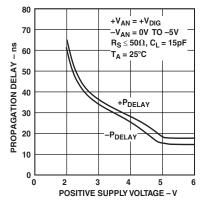
TPC 6. CMP402 Propagation Delay vs. Temperature – 20 mV OD



TPC 7. CMP401 Propagation Delay vs. Source Resistance – 20 mV OD



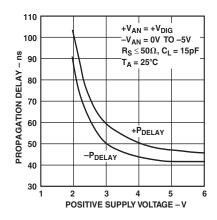
TPC 8. CMP402 Propagation Delay vs. Source Resistance – 20 mV OD



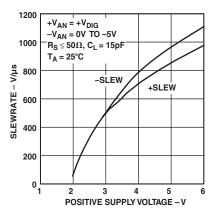
TPC 9. CMP401 Propagation Delay vs. Supply Voltage – 20 mV OD

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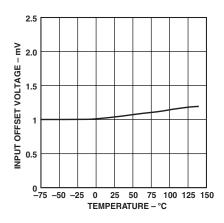
CMP401/CMP402



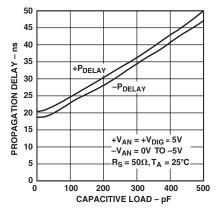
TPC 10. CMP402 Propagation Delay vs. Supply Voltage – 20 mV OD



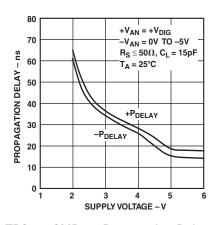
TPC 13. CMP401/CMP402 Slew Rate vs. Positive Supply Voltage



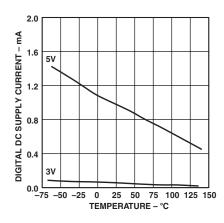
TPC 16. CMP401/CMP402 Input Offset Voltage vs. Temperature



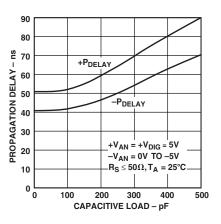
TPC 11. CMP401 Propagation Delay vs. Capacitive Load



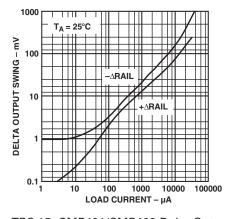
TPC 14. CMP401 Propagation Delay vs. Supply Voltage



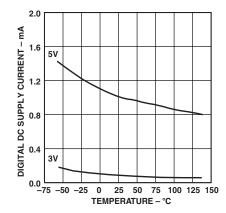
TPC 17. CMP401 Digital Supply Current vs. Temperature



TPC 12. CMP402 Propagation Delay vs. Capacitive Load



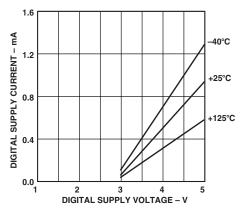
TPC 15. CMP401/CMP402 Delta Output Swing from Power Supplies vs. Load Current



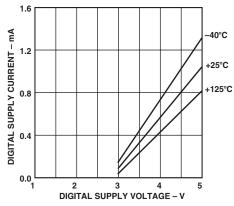
TPC 18. CMP402 Digital Supply Current vs. Temperature

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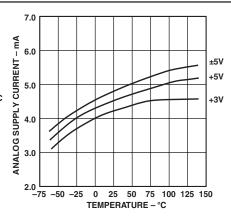
Typical Performance Characteristics—CMP401/CMP402



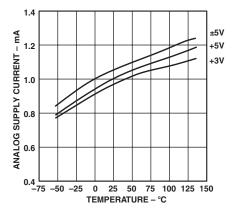
TPC 19. CMP401 Digital Supply Current vs. Digital Supply Voltage



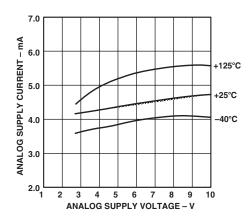
TPC 20. CMP402 Digital Supply Current vs. Digital Supply Voltage



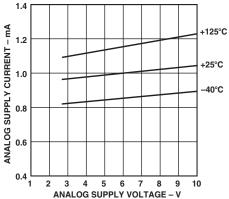
TPC 21. CMP401 Analog Supply Current vs. Temperature



TPC 22. CMP402 Analog Supply Current vs. Temperature



TPC 23. CMP401 Analog Supply Current vs. Analog Supply Voltage

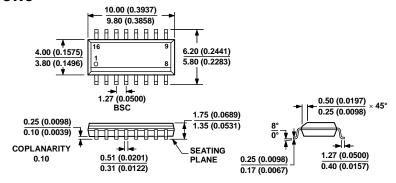


TPC 24. CMP402 Analog Supply Current vs. Analog Supply Voltage

REV. B -7-

CMP401/CMP402 **Data Sheet**

OUTLINE DIMENSIONS

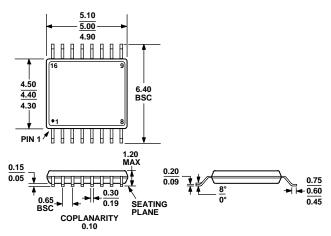


COMPLIANT TO JEDEC STANDARDS MS-012-AC

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 1. 16-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-16)S-Suffix

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 2. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16) Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
CMP401GRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
CMP401GSZ	-40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP401GSZ-REEL	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP402GRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
CMP402GSZ	-40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP402GSZ-REEL	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16

¹ Z = RoHS Compliant Part.



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